

Improved Quad SPST CMOS Analog Switches

DESCRIPTION

The DG444B, DG445B are monolithic quad analog switches designed to provide high speed, low error switching of analog and audio signals. The DG444B, DG445B are upgrades to the original DG444, DG445.

Combining low on-resistance ($45\ \Omega$, typ.) with high speed (t_{on} 120 ns, typ.), the DG444B, DG445B are ideally suited for data acquisition, communication systems, automatic test equipment, or medical instrumentation. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

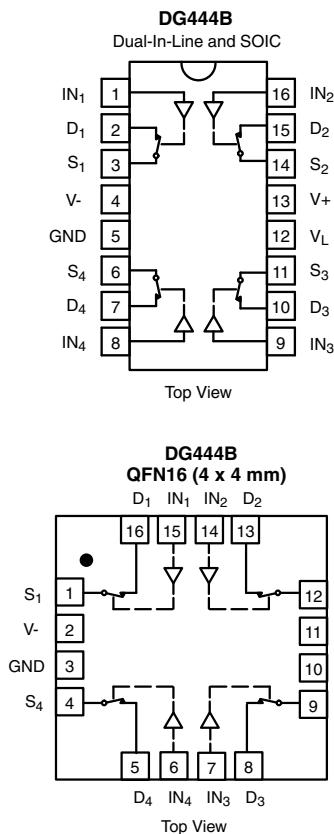
The DG444B, DG445B are built using Vishay Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

When on, each switch conducts equally well in both directions and blocks input voltages to the supply levels when off.

BENEFITS

- Low signal errors and distortion
- Reduced power supply consumption
- Faster throughput
- Reduced pedestal errors
- Simple interfacing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



FEATURES

- Low on-resistance: $45\ \Omega$
- Low power consumption: 1 mW
- Fast switching action - t_{on} : 120 ns
- Low charge injection
- TTL/CMOS-compatible logic
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Audio switching
- Data acquisition
- Sample-and-hold circuits
- Communication systems
- Automatic test equipment
- Medical instruments

TRUTH TABLE

LOGIC	DG444B	DG445B
0	On	Off
1	Off	On

Note

- Logic "0" $\leq 0.8\text{ V}$
- Logic "1" $\geq 2.4\text{ V}$

ORDERING INFORMATION

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	16-pin narrow SOIC	DG444BDY-E3
		DG444BDY-T1-E3
		DG445BDY-E3
		DG445BDY-T1-E3
	16-pin QFN 4 x 4 mm (variation 1)	DG444BDN-T1-E4
		DG445BDN-T1-E4

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
V+ to V-		44	V
GND to V-		25	
VL		(GND - 0.3 V) to (V+) + 0.3 V	
Digital inputs ^a , V_S , V_D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Continuous current (any terminal)		30	
Current, S or D (pulsed at 1 ms, 10 % duty cycle)		100	mA
Storage temperature		-65 to +125	
Power dissipation (package) ^b	16-pin narrow body SOIC ^d	640	mW
	QFN-16 ^e	850	

Notes

- a. Signals on S_x , D_x , or I_{N_x} exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 6 mW/ $^\circ\text{C}$ above 75 $^\circ\text{C}$
- d. Derate 8 mW/ $^\circ\text{C}$ above 75 $^\circ\text{C}$
- e. Derate 12 mW/ $^\circ\text{C}$ above 75 $^\circ\text{C}$

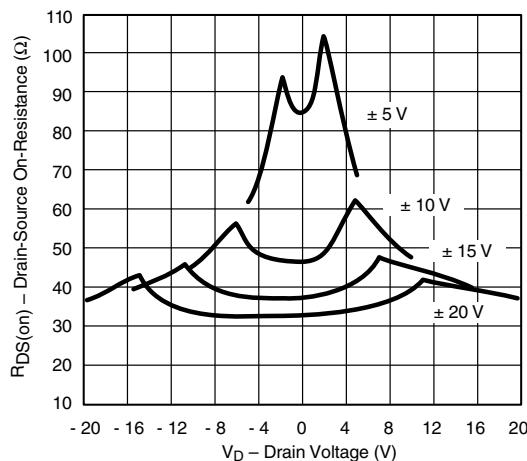
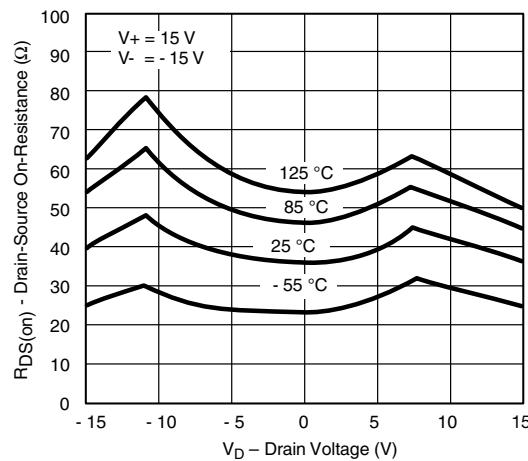
SPECIFICATIONS (for dual supplies)							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_+ = 15 \text{ V}$, $V_- = -15 \text{ V}$ $V_L = 5 \text{ V}$, $V_{IN} = 2.4 \text{ V}$, 0.8 V^e	TEMP. ^a	D SUFFIX -40 $^\circ\text{C}$ TO +85 $^\circ\text{C}$			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
Analog Switch							
Analog signal range ^d	V_{ANALOG}		Full	-15	-	15	V
Drain-source on-resistance	$R_{DS(on)}$	$I_S = 1 \text{ mA}$, $V_D = \pm 10 \text{ V}$	Room	-	45	80	Ω
Switch off leakage current	$I_{S(off)}$		Full	-	-	95	
	$I_{D(off)}$	$V_D = \pm 14 \text{ V}$, $V_S = \pm 14 \text{ V}$	Room	-0.5	± 0.01	0.5	nA
Channel on leakage current	$I_{D(on)}$		Full	-5	-	5	
		$V_S = V_D = \pm 14 \text{ V}$	Room	-0.5	± 0.02	0.5	
			Full	-10	-	10	
Digital Control							
Input, low voltage	V_{INH}		Full	-	-	0.8	V
Input, high voltage	V_{INL}		Full	2.4	-	-	
Input current V_{IN} low	I_{INL}	V_{IN} under test = 0.8 V, all other = 2.4 V	Full	-1	-0.01	1	μA
Input current V_{IN} high	I_{INH}	V_{IN} under test = 2.4 V, all other = 0.8 V	Full	-1	0.01	1	
Dynamic Characteristics							
Turn-on time	t_{on}	$R_L = 1 \text{ k}\Omega$, $C_L = 35 \text{ pF}$, $V_S = \pm 10 \text{ V}$, See figure 2	Room	-	-	300	ns
Turn-off time	t_{off}		Room	-	-	200	
Charge injection ^e	Q	$C_L = 1 \text{ nF}$, $V_S = 0 \text{ V}$, $V_{gen} = 0 \text{ V}$, $R_{gen} = 0 \Omega$	Room	-	1	-	pC
Off isolation ^e	OIRR	$R_L = 50 \Omega$, $CL = 15 \text{ pF}$, $v = 1 \text{ V}_{\text{RMS}}$, $f = 100 \text{ kHz}$	Room	-	-90	-	dB
Crosstalk (channel-to-channel) ^d	X_{TALK}		Room	-	-95	-	
Source off capacitance	$C_{S(off)}$	$V_S = 0 \text{ V}$, $f = 100 \text{ kHz}$	Room	-	5	-	pF
Drain off capacitance	$C_{D(off)}$		Room	-	5	-	
Channel on capacitance	$C_{D(on)}$	$V_S = V_D = 0 \text{ V}$, $f = 1 \text{ MHz}$	Room	-	16	-	
Power Supplies							
Positive supply current	I_+	$V_{IN} = 0 \text{ V}$ or 5 V	Room	-	-	1	μA
Negative supply current	I_-		Full	-	-	5	
Logic supply current	I_{IN}		Room	-1	-	-	
			Full	-5	-	-	
			Room	-	-	1	
			Full	-	-	5	

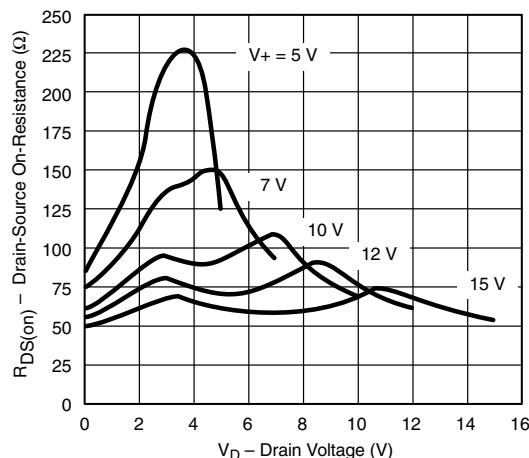
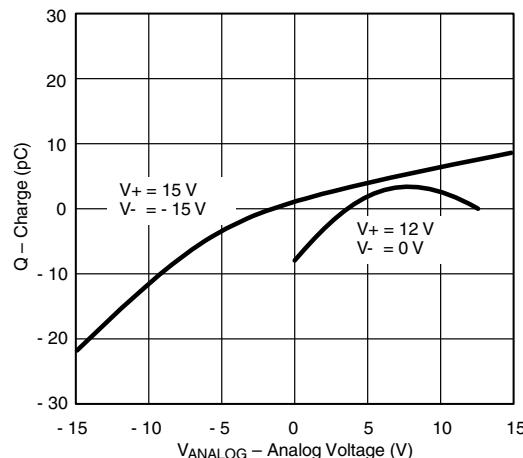
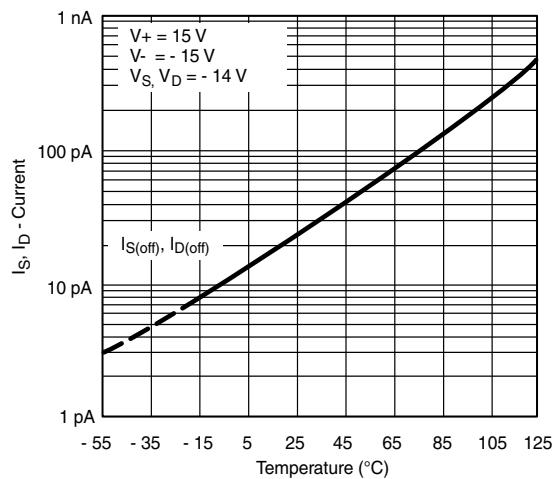
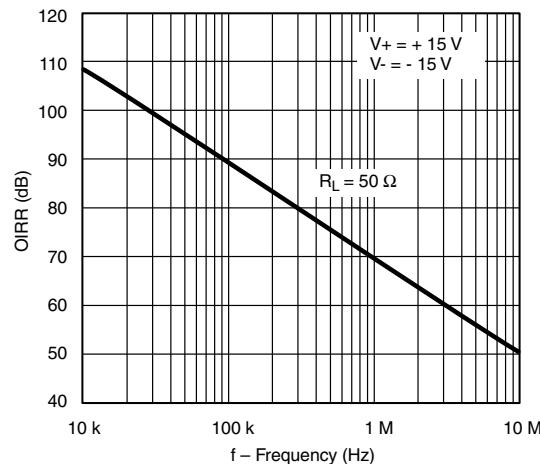
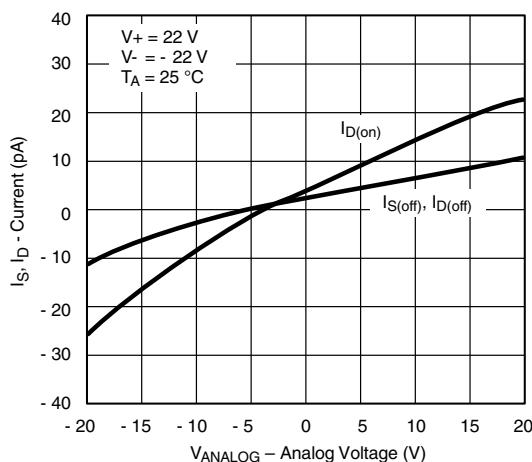
SPECIFICATIONS (for unipolar supplies)		TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $V_+ = 12 \text{ V}$, $V_- = 0 \text{ V}$ $V_L = 5 \text{ V}$, $V_{IN} = 2.4 \text{ V}$, 0.8 V^e		TEMP. ^a	D SUFFIX -40 °C TO +85 °C			UNIT
PARAMETER	SYMBOL	MIN. ^b	TYP. ^c	MAX. ^b				
Analog Switch								
Analog signal range ^d	V_{ANALOG}	Full	0	-	12	-	V	
Drain-source on-resistance ^d	$R_{DS(on)}$	$I_S = 1 \text{ mA}$, $V_D = 3 \text{ V}$, 8 V	Room	-	90	160	Ω	
			Full	-	-	200		
Dynamic Characteristics								
Turn-on time	t_{on}	$R_L = 1 \text{ k}\Omega$, $C_L = 35 \text{ pF}$, $V_S = 8 \text{ V}$, See Fig. 2	Room	-	120	300	ns	
Turn-off time	t_{off}		Room	-	60	200		
Charge Injection	Q	$C_L = 1 \text{ nF}$, $V_{gen} = 6 \text{ V}$, $R_{gen} = 0 \Omega$		Room	-	4	-	pC
Power Supplies								
Positive supply current	I_+	$V_{IN} = 0 \text{ V}$ or 5 V	Room	-	-	1	μA	
			Full	-	-	5		
Negative supply current	I_-		Room	-1	-	-		
			Full	-5	-	-		
Logic supply current	I_{IN}	$V_L = 5.25 \text{ V}$, $V_{IN} = 0 \text{ V}$ or 5 V	Room	-	-	1	μA	
			Full	-	-	5		

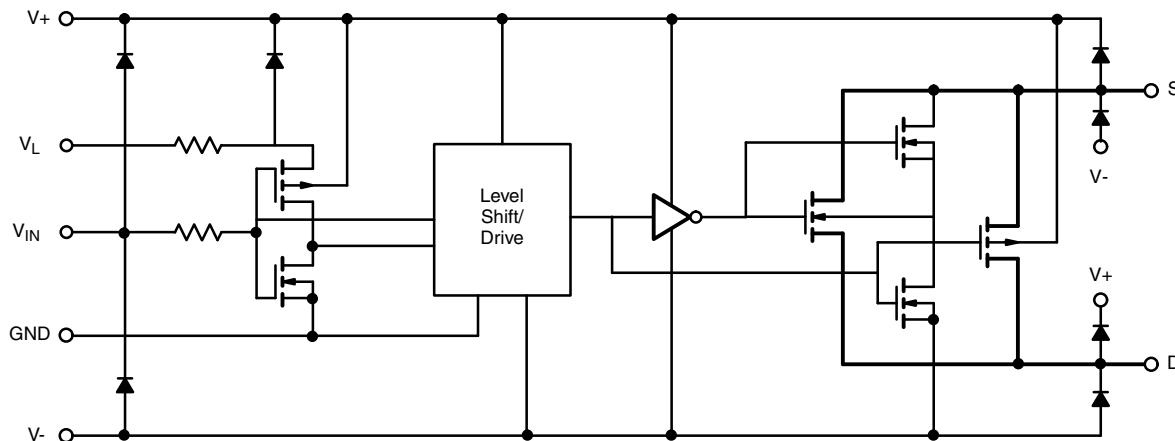
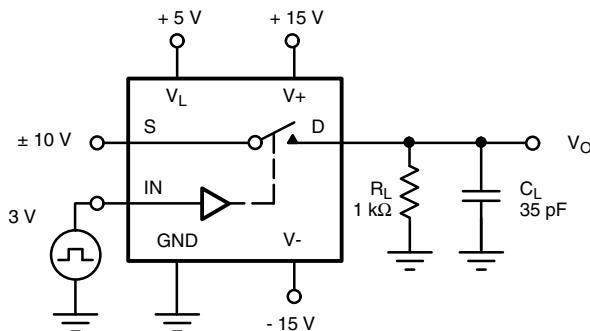
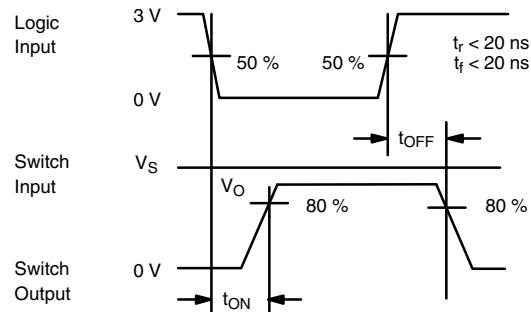
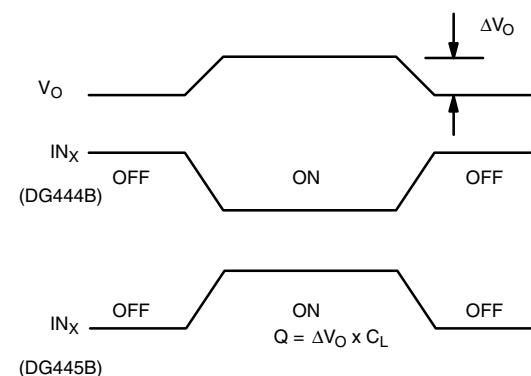
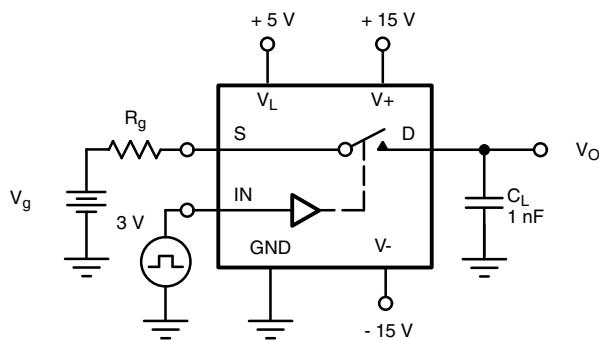
Notes

- a. Room = 25 °C, full = as determined by the operating temperature suffix
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. Guaranteed by design, not subject to production test
- e. V_{IN} = input voltage to perform proper function

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ }^\circ\text{C}$, unless otherwise noted)

R_{DS(on)} vs. V_D and Power Voltages

R_{DS(on)} vs. V_D and Temperature

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

 $R_{DS(on)}$ vs. V_D and Single Power Supply Voltages

 Q_s, Q_d - Charge Injection vs. Analog Voltage

Leakage Current vs. Temperature

Off Isolation vs. Frequency

Leakage Currents vs. Analog Voltage

SCHEMATIC DIAGRAM (typical channel)

Fig. 1
TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

Fig. 2 - Switching Time

Fig. 3 - Charge Injection

TEST CIRCUITS

C = 1 mF tantalum in parallel with 0.01 mF ceramic

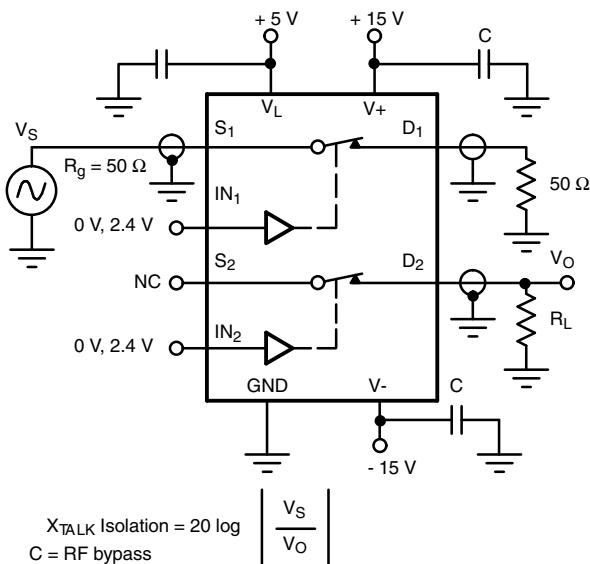


Fig. 4 - Crosstalk

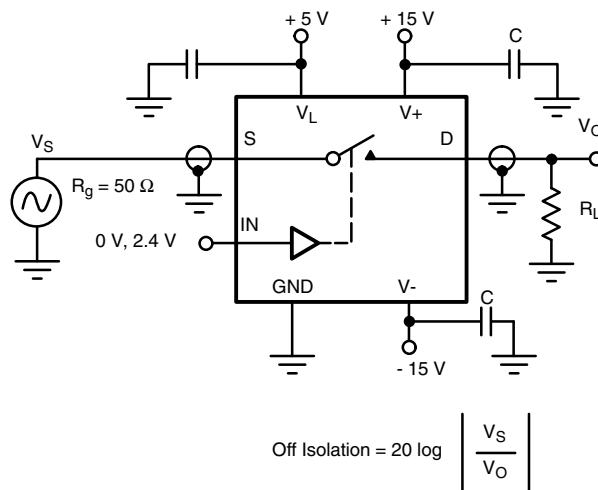


Fig. 5 - Off Isolation

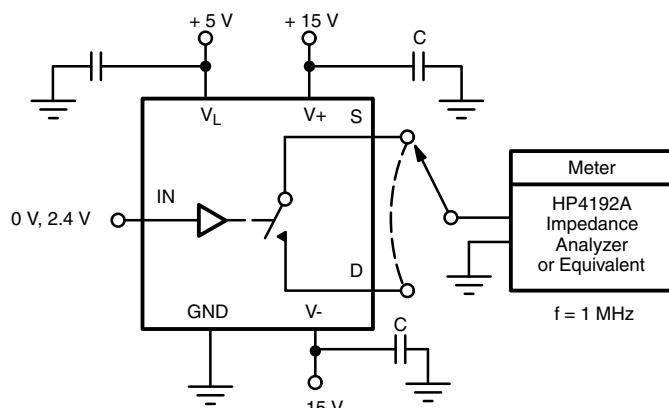


Fig. 6 - Source/Drain Capacitances

APPLICATIONS

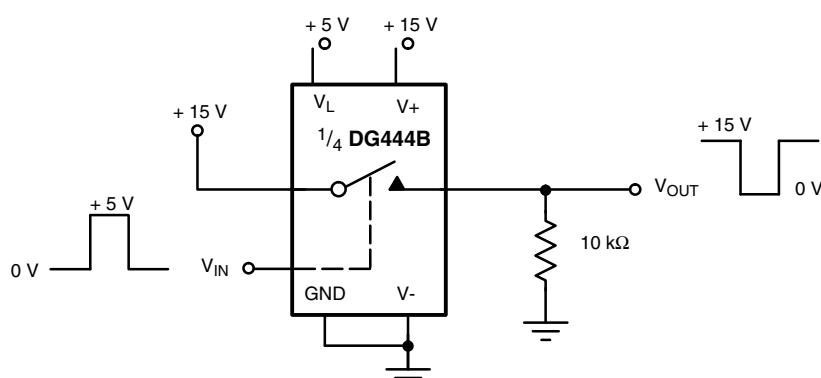
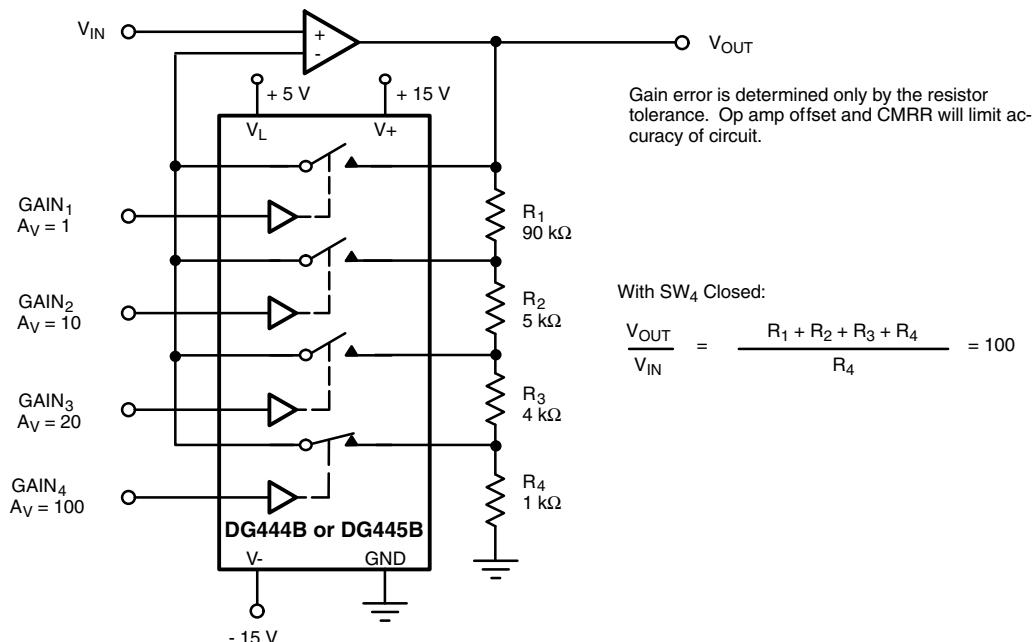
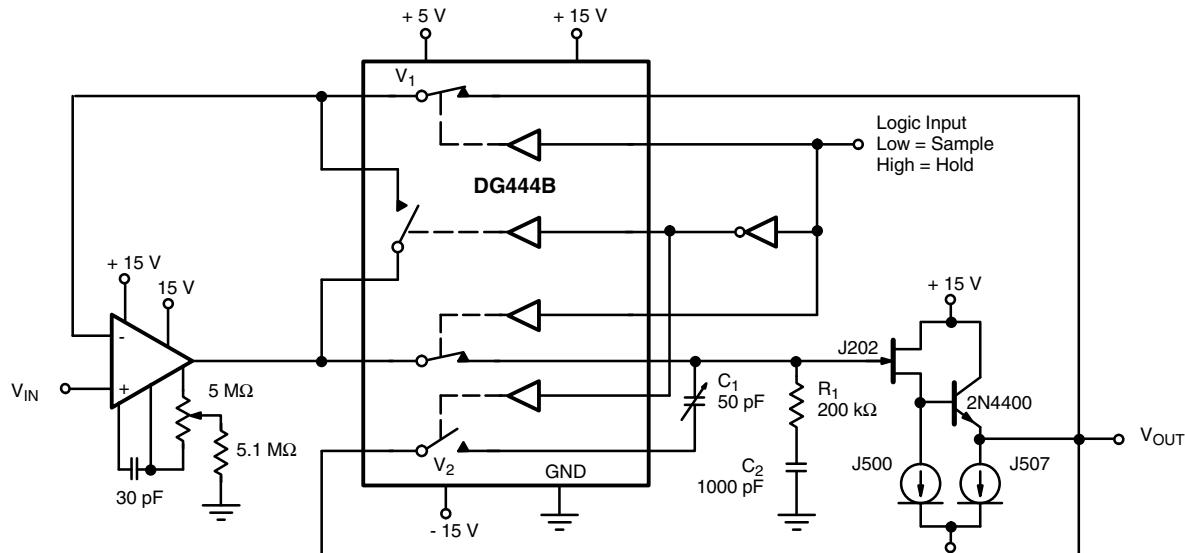


Fig. 7 - Level Shifter

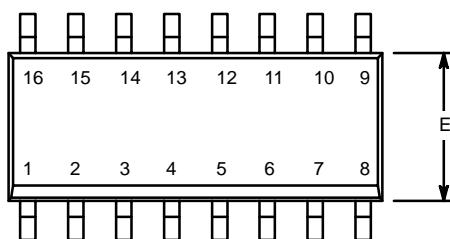
APPLICATIONS

Fig. 8 - Precision-Weighted Resistor Programmable-Gain Amplifier

Fig. 9 - Precision Sample-and-Hold

PRODUCT SUMMARY				
Part number	DG444B	DG444B	DG445B	DG445B
Status code	2	2	2	2
Configuration	SPST x 4, NC	SPST x 4, NC	SPST x 4, NO	SPST x 4, NO
Single supply min. (V)	5	5	5	5
Single supply max. (V)	36	36	36	36
Dual supply min. (V)	5	5	5	5
Dual supply max. (V)	22	22	22	22
On-resistance (Ω)	45	45	45	45
Charge injection (pC)	1	1	1	1
Source on capacitance (pF)	16	16	16	16
Source off capacitance (pF)	5	5	5	5
Leakage switch on typ. (nA)	0.02	0.02	0.02	0.02
Leakage switch off max. (nA)	0.5	0.5	0.5	0.5
-3 dB bandwidth (MHz)	-	-	-	-
Package	SO-16 (narrow) AS	QFN-16 4 x 4	SO-16 (narrow) AS	QFN-16 4 x 4
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare
Interface	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes
Turn on time max. (ns)	300	300	300	300
Crosstalk and off isolation	-90	-90	-90	-90

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72626.

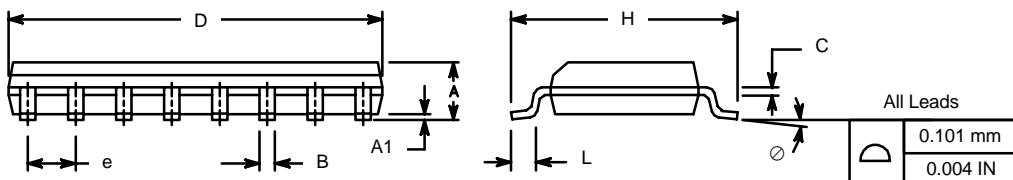
SOIC (NARROW): 16-LEAD

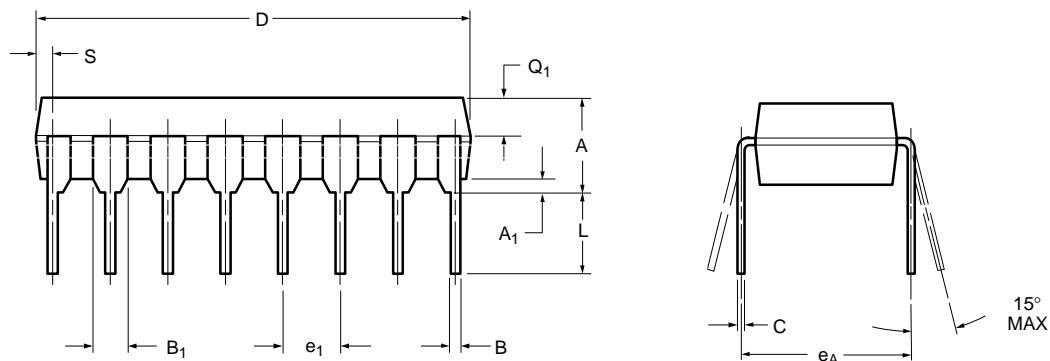
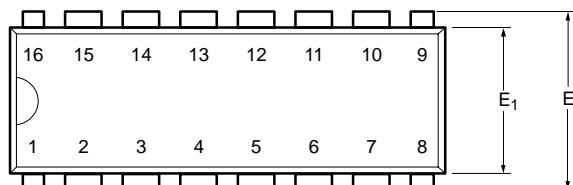
JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
\emptyset	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300

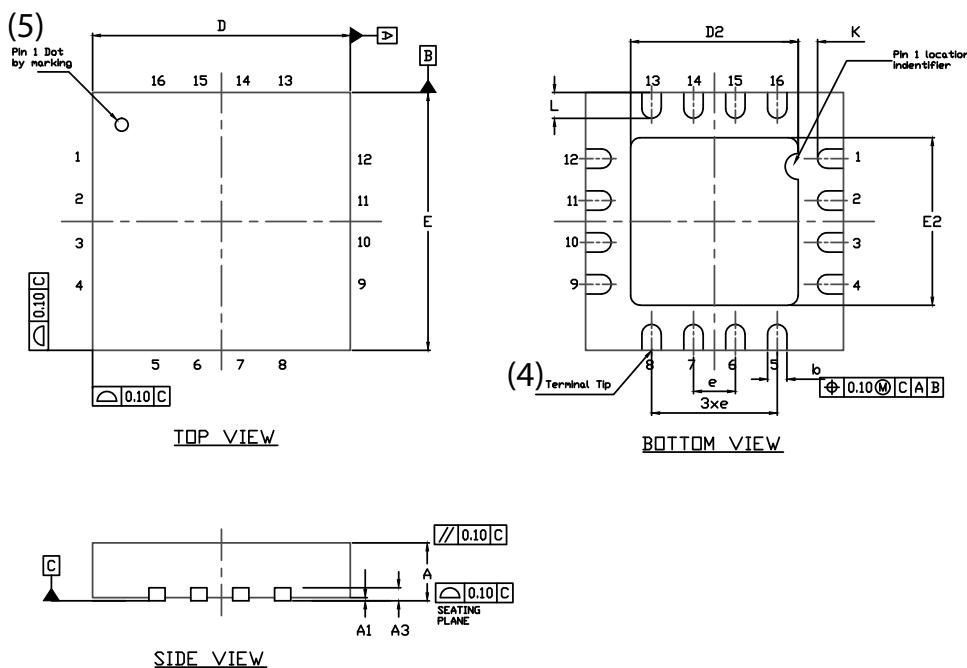


PDIP: 16-LEAD


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

QFN 4x4-16L Case Outline



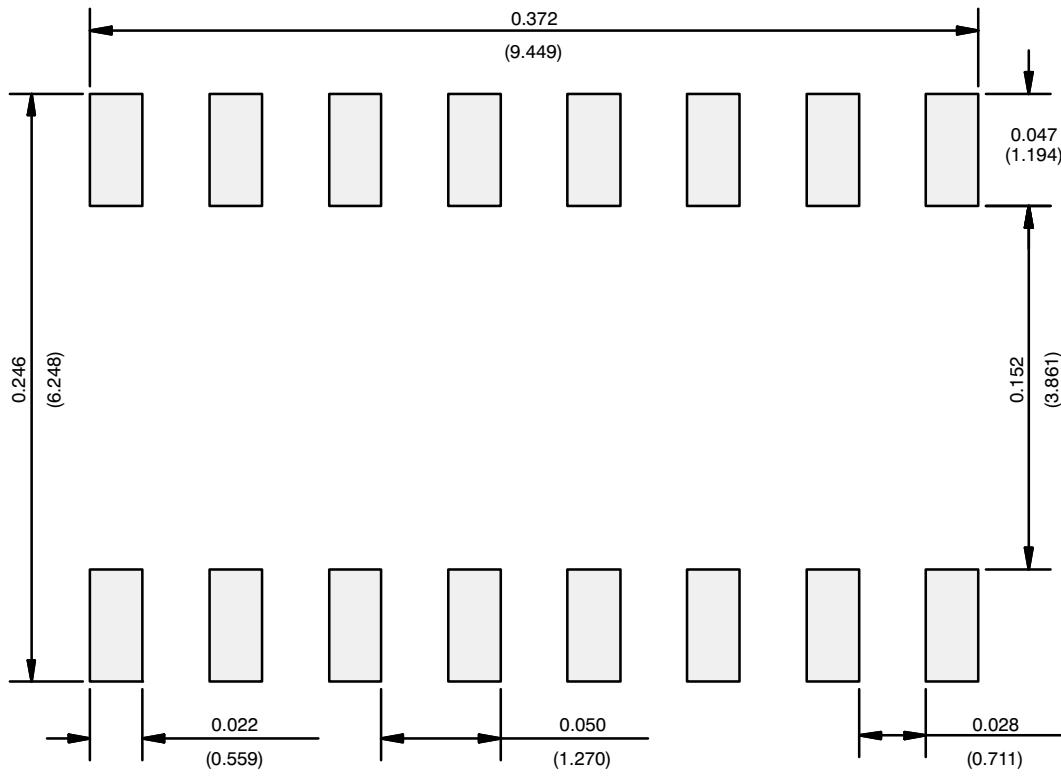
DIM	VARIATION 1						VARIATION 2					
	MILLIMETERS(1)			INCHES			MILLIMETERS(1)			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
A3	0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.		
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.012	0.014
D	4.00 BSC			0.157 BSC			4.00 BSC			0.157 BSC		
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
e	0.65 BSC			0.026 BSC			0.65 BSC			0.026 BSC		
E	4.00 BSC			0.157 BSC			4.00 BSC			0.157 BSC		
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106
K	0.20 min.			0.008 min.			0.20 min.			0.008 min.		
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020
N ⁽³⁾	16			16			16			16		
Nd ⁽³⁾	4			4			4			4		
Ne ⁽³⁾	4			4			4			4		

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

ECN: S13-0893-Rev. B, 22-Apr-13
DWG: 5890

RECOMMENDED MINIMUM PADS FOR SO-16



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